PREPARED BY:	DATE:		SPEC. No. ED-96166X
y. Oda	.,	SHARP	ISSUE October 23, 1996
<u>Vct, 2</u>	4,1996		PAGE Pages
APPROVED BY:	DATE:	ELECTRONIC COMPONENTS GROUP SHARP CORPORATIO	N REPRESENTATIVE DIVISION
O. Ohlikava d	Oct 11, 1996	SPECIFICATION	OPTO-ELECTRONIC DEVICES DIV
			OPTO-ELECTRONIC DEVICES DIV
DEMA	DEVICE	SPECIFICATION FOR	
DEMA Electronic GmbH	1	PHOTOINTERRUPTER	
Türkenstr. 11 D 80333 München	MODEL	No.	
info@dema.net, http://dema.net		GP1A71A	}
Tel.: +49 (89) 28 69 41-0 Fax.: +49 (89) 28 35 09			
		ude materials protected under copyrig use anyone to reproduce them without	
in these specifi for any damage	ication sheets, a e resulting from	as well as the precautions mentioned b	ngs and the instructions for use outlined lelow. Sharp assumes no responsibility mply with the absolute maximum ratings precautions mentioned below.
(Precautions			
	-	gned for use in the following application	
	= =	 Audio visual equipment Home appoint equipment (Terminal) Measuring 	oliances gequipment
L· To	ooling machines	• Computers	
If th (2) o	e use of the pro or (3), please be	duct in the above application areas is sure to observe the precautions given:	for equipment listed in paragraphs in those respective paragraphs.
the sa and s	afety design of t afety when this	es, such as fail-safe design and redund he overall system and equipment, show product is used for equipment which of d precision, such as ;	ıld be taken to ensure reliability
		ontrol and safety equipment (aircraft, to	
I	ther safety equi	Gas leakage sensor breakers · Resc pment	ue and security equipment
		is product for equipment which require and precision, such as ;	e extremely high reliability
[·s _t	oace equipment	 Telecommunication equipment (for ntrol equipment · Medical equipmen) 	
(4) Pleas	e contact and c	onsult with a Sharp sales representativ	-
		ion of the above three paragraphs.	
3. Please contact	and consult wit	h a Sharp sales representative for any	
CUSTOMER	'S APPROVAL	DATE PRESI BY	Oct. 24, 1996 O. Schihawa
DATE			L. Ebina, Chief Manager of
		C	pto-System Project Team
BY	. 1280		Opto-Electronic Devices Div. CLECOM Group
			HARP CORPORATION
		· 	·

October 23, 1996 MODEL NO. 1/10

1. Application

This specification applies to the outline and characteristics of transmissive type. photointerrupter with connector; Model No. GP1A71A.

2. Outline

Refer to the attached drawing No. CY4070i02.

3. Ratings and characteristics

Refer to the attached sheet, page 5 to 7.

4. Reliability

Refer to the attached sheet, page 8.

5. Outgoing inspection

Refer to the attached sheet, page 9.

- 6. Supplements
 - · Parts: Refer to the attached sheet, page 10.
- 7. Notes
 - 7.1 Truth table (In case of external addition pull-up resistance to Vout terminal)

Light beam	Output
Interrupted	High
Uninterrupted	Low

- 7.2 In order to stabilize power supply line, connect a by-pass capacitor of more than 0.01 μ F between Vcc and GND near the device.
- 7.3 Please don't carry out immersion cleaning or ultrasonic cleaning to avoid keeping solvent inside case of this device.
- 7.4 Dust and stain shall clean by air blow, or shall clean by soft cloth soaked in washing materials. And washing material to clean shall be used the below materials only.

Ethyl alcohol, Methyl alcohol, Isopropyl alcohol

Before you use alternative solvent you are requested to confirm that it does not damage package resin.

ED-96166X October 23, 1996

MODEL N. PAGE
2/10

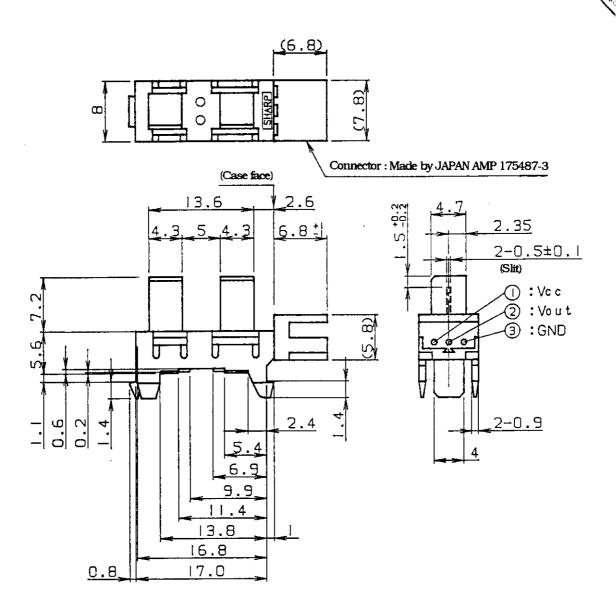
2. Outline (Drawing No. CY4070i02)

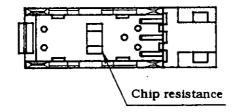
Scale: 2/1

Unit:1/1mm

Note) 1. Unspecified tolerance shall be followed the list below.

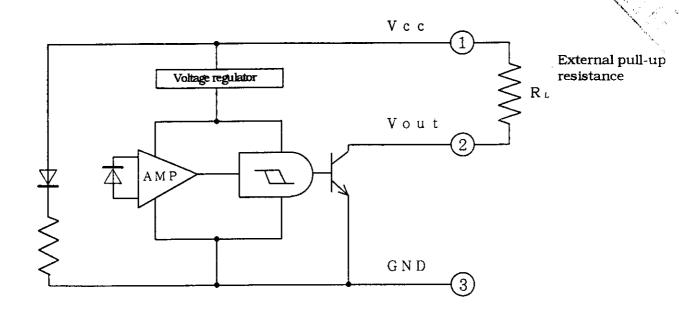
2. Dimensions in parenthesis are shown for reference.



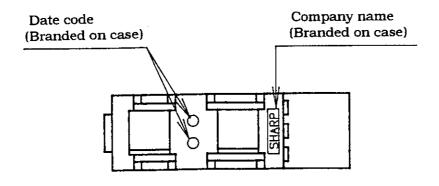


Dimension	Tolerance
below 5.0	±0.15
5.0 or more to below 15.0	±0.2
15.0 or more	±0.3

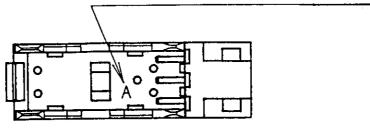
2-1. Internal connection diagram



2-2. Marking drawing



Model No. (Abbreviation: Indicated on PCB)



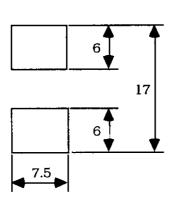
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ED-961662	October 23, 1996
MODEL NO	PAGE
CALAZ	1 4/10
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2-3 Recommendation Installation Hole drawing

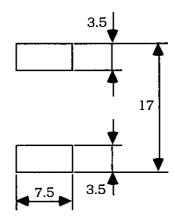
Scale: 2/1

Unit : 1/1mm

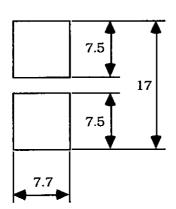
- *1 Dimensions are typical value.
- *2 We recommend to fix GP1A71A at punching side on the fixing plate (metal plate).
- *3 The below dimensions are reference. Please decide the final dimensions at your side after confirmation by the actual applications.



Thickness of plate for 1.2mm



Thickness of plate for 1.0mm



Thickness of plate for 1.6mm

tober 23, 1996 MODEL No. PAGE 5/10

3-1 Absolute maximum ratings

Ta=	25°C
ıa-	حعرف

Parameter	Symbol	Rating	Unit	Remark
Supply voltage	Vcc	-0.5 to +10	V	
Output voltage	Vout	-0.5 to +28	V	Output transistor between collector and emitter
Output current	I _{OL}	50	mA	Output transistor collector current *1
Operating temperature	Topr	-20 to +75	င	The connector should be plugged in/out at normal
Storage temperature	Tstg	-30 to +85	ာ	temperature.

st Fig.1 shows output current vs. ambient temperature.

3-2 Electro-optical characteristics

Vcc=5V, Ta=25℃

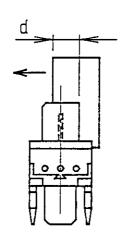
Parameter		Symbol	Rating	Unit	Conditions
Current dis	sipation	I _{CCL}	16.5 MAX.	mA	Light beam uninterrupted
Low level output voltage		V _{OL}	0.35 MAX.	V	Light beam uninterrupted I _{OL} =16mA
Current dissipation		I _{CCH}	16.5 MAX.	mA	Light beam interrupted
High level output voltage		V _{OH}	(Vcc×0.9) MIN.	V	Light beam interrupted R_L =47k Ω
Operating v	Operating voltage		4.5 to 5.5	V	
Response	Min. inter- rupted time	t _H	166 MIN.	μS	R ₁ =4.7k Ω
istics	Min. uninter- rupted time	t _L	166 MIN.	μS	1V-7.1A 22

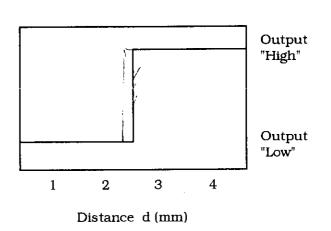
ED-96166% October 23, 1996

MODEL No. PAGE
6/10

3-3 Detecting position characteristics (Ta=25 °C, Vcc=5V, R_L =47k Ω)

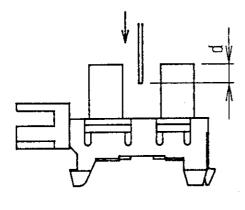
 $d=2.35\pm0.3$ mm





3-4 Detecting position characteristics (Ta=25 °C, Vcc=5V, R_L =47k Ω)

 $d=3.0\pm1.0$ mm



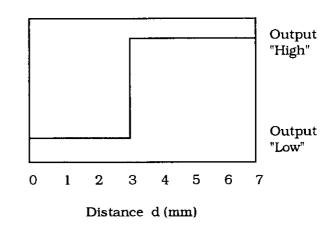
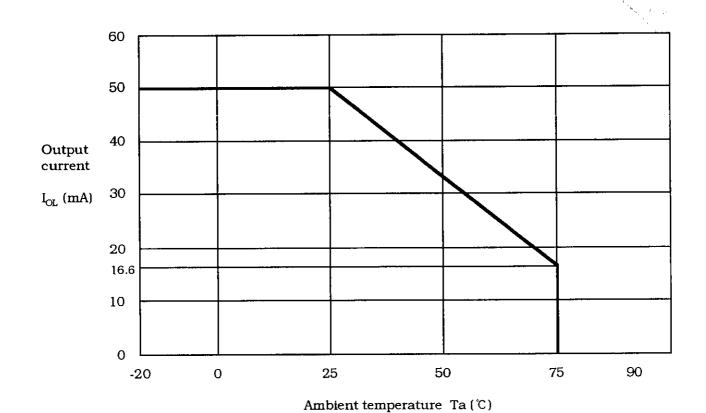


Fig.1 Output current vs. ambient temperature



ED-96166X	Octobe	r 23, 1996
MODELINE.		PAGE
GP)A7	lA	8/10

4. Reliability

The reliability of products shall be satisfied with items listed below.

Confidence level 90%/LTPD: 10%/20%

Test item	Test conditions	Failure Judgement Criteria	Samples (n) Defective(C)
Temperature cycling	1 cycle -30°C to +85°C (20min) (20min) 5 cycles test	I _{CCL} ≧U×1.2	n=22, C=0
High temp. and high humidity storage	+40°C, 90%RH, 240h	I _{CCH} ≧U×1.2	n=22, C=0
High temp. storage	Without connector +85℃, 240h	V _{OL} ≧U×1.2	n=22, C=0
Low temp. storage	-30℃, 240h	V _{OH} ≦L×0.8	n=22, C=0
Operation life	Vcc=5V, Ta=25±3℃, 1000h	II. IImmor	n=22, C=0
Mechanical shock	1000m/s², 3 times/ X, Y, Z direction	U : Upper specification limit	n=11, C=0
Variable vibration frequency	Overall amplitude ; 1.5mm Frequency range 10 to 55 to 10 Hz/1 min 2h/ X, Y, Z direction	L : Lower specification limit	n=11, C=0
Pull connector housing Connector horizontally to connector strength I terminal pin direction by 20N weight for 5 s (1 time)		Abnormal electrical	n=11, C=0
Connector strength II	Push connector housing perpendicular to connect- or terminal pin direction by 10N weight for 5 s (1 time)	electrical characteristics	n=11, C=0

October 23, 1996 PAGE 9/10

5. Outgoing inspection

	Item	Conditions	Instrument	Judge, Criteria	AGE COA
1	Appearance	No defects that may conflict with product specifications, including crack, split, chip scratch, burr and blur, No bent connector pin and loosened pin	Visual inspection	Any of the specified defects at left is not acceptable	1.0
2	Electrical charac- teristics	Specified in para 3-2 (I _{CCL} , V _{OL} , I _{CCH} , V _{OH} ,Vcc)	Dedicated tester	Specimen that does not satisfied the requirements specified at left is not acceptable.	0.4

A single sampling plan, normal inspection level $\, \mathrm{II} \,$ based on ISO 2859 shall be adopted.

October 23, 1996 MODEL No. PAGE GRLA71A 10/10

6. Supplements

· Parts: This product uses the below parts.

6-1 Light detector (IS487, Q'ty: 1)

(Using a silicon photodiode as light detecting portion, and a bipolar IC as signal processing circuit.)

Туре	Maximum sensitivity wavelength (nm)	Sensitivity wavelength (nm)	Response time (μ s)
Photodiode	900	400 to 1200	3

6-2 Light emitter (GL480, Q'ty: 1)

Туре	Material	Maximum light emitting wavelength (nm)	I/O Frequency (MHz)
Infrared light emitting diode (Non-coherent)	GaAs	950	0.3

6-3 Material

Case
Black polycarbonate resin
(UL 94V-2)

6-4 Others

This product shall not be proof against radiation flux.

Laser generator is not used.